IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Inventor(s): Pan et al.

Patent No.: 6,936,897 B2

Issued: August 30, 2005

For: INTERMEDIATE STRUCTURE
HAVING A SILICON NITRIDE BARRIER
LAYER ENCAPSULATING A

LAYER ENCAPSULATING A SEMICONDUCTOR SUBSTRATE

Attorney Docket No.: 2269-3027.2US

VIA ELECTRONIC FILING

September 6, 2007

REQUEST FOR CERTIFICATE OF CORRECTION OF PATENT FOR APPLICANTS' MISTAKES (37 C.F.R. § 1.323) AND PATENT OFFICE MISTAKES (37 C.F.R. § 1.322)

Attn.: Certificate of Corrections Branch Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

It is noted that a combination of Applicant and Patent Office errors appear in this patent of a typographical nature or character and correction thereof does not involve such changes in the patent as would constitute new matter or would require reexamination. A certificate of correction in the form attached hereto is requested.

Please send the Certificate to:

Name:

Joseph A. Walkowski

Address:

TraskBritt

P.O. Box 2550

Salt Lake City, Utah 84110

The Commissioner is authorized to charge \$100.00 to the TraskBritt Deposit Account No. 20-1469 for the fee as required by 37 C.F.R. § 1.20(a).

Attached hereto is Form PTO/SB/44, which is suitable for printing.

Respectfully submitted,

Joseph A. Walkowski Registration No. 28,765

Attorney for Applicant(s)

TRASKBRITT P.O. Box 2550

Salt Lake City, Utah 84110-2550

Telephone: 801-532-1922

Date: September 6, 2007

JAW/csw

Attachments: PTO/SB/44

Document in ProLaw

UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO : 6,936,897 B2 Page 1 of 4

APPLICATION NO. : 09/259,145

ISSUE DATE : August 30, 2005

INVENTOR(S) : Pai-Hung Pan and Nanseng Jeng

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the title page:

In Item (54) TITLE change "INTERMEDIATE STRUCTURE HAVING A

SILICON BARRIER LAYER ENCAPSULATING A

SEMICONDUCTOR SUBSTRATE" to

--INTERMEDIATE STRUCTURE HAVING A

SILICON NITRIDE BARRIER LAYER ENCAPSULATING A SEMICONDUCTOR

SUBSTRATE--

In ITEM (57) **ABSTRACT**, 12th line, change "unmasked potion" to --unmasked portions--

In the drawings:

In FIG. 1, replace existing drawing (with Examiner's notations) with

the replacement (clean) drawing

In FIG. 4, add two occurrences of reference numeral --124--

In the specification:

COLUMN 1, LINE 2, change "SILICON BARRIER LAYER" to --SILICON

NITRIDE BARRIER LAYER--

COLUMN 1, LINE 38, change "layer 210 maybe" to --layer 210 may be--

COLUMN 2, LINE 24, change "(see U.S. Pat." to --(see U.S. Pat.--

MAILING ADDRESS OF SENDER (Please do not use customer number below):

Katherine A. Hamer TRASKBRITT 230 South 500 East, Suite 300 Salt Lake City, Utah 84102 USA

UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO : 6,936,897 B2 Page 2 of 4

APPLICATION NO.: 09/259,145

ISSUE DATE : August 30, 2005

INVENTOR(S) : Pai-Hung Pan and Nanseng Jeng

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

In the claims:

CLAIM 9, COLUMN 7, LINE 28, change "first substrate" to --first surface--

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UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO : 6,936,897 B2 Page 3 of 4

APPLICATION NO. : 09/259,145

ISSUE DATE : August 30, 2005

INVENTOR(S) : Pai-Hung Pan and Nanseng Jeng

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Please replace FIG. 1 with the following replacement figure:

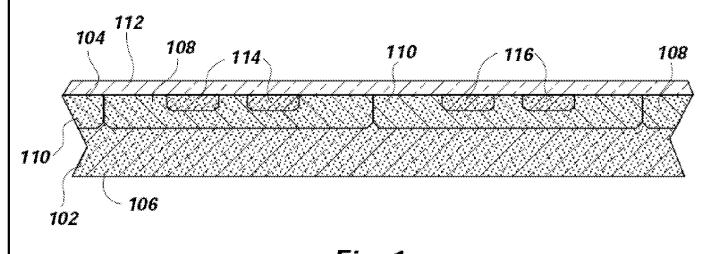


Fig. T

MAILING ADDRESS OF SENDER (Please do not use customer number below):

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UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

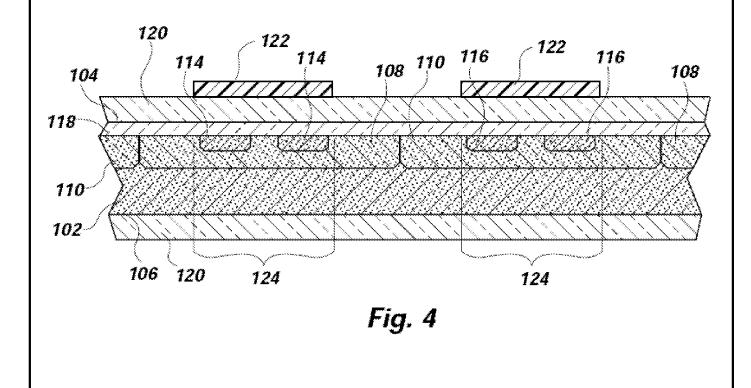
PATENT NO : 6,936,897 B2 Page 4 of 4

APPLICATION NO. : 09/259,145
ISSUE DATE : August 30, 2005

INVENTOR(S) : Pai-Hung Pan and Nanseng Jeng

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Please replace FIG. 4 with the following amended figure:



MAILING ADDRESS OF SENDER (Please do not use customer number below):

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